## EFFECTS OF GRAIN SIZE REDUCTION ON THE ELECTROANALYTICAL PERFORMANCE OF CONDUCTIVE DIAMOND ELECTRODE DEPOSITED IN $CH_4/H_2\ GAS\ MIXTURE$

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## Abstract

Diamond is one of the most recent carbon allotropes to find utility in electrochemical analysis. Boron-doped polycrystalline diamond planar electrodes synthesized by chemical vapor deposition (CVD) methods exhibit many properties of an excellent electrode such as low non-Faradaic current over a wide working potential window, quasireversible to reversible kinetics and large signal-to-background ratio for several redox system without need for surface pretreatment, excellent morphological and structural stability at extreme potentials and current densities, and long-term stability [1]. In addition, its resistance to surface fouling and chemical inertness also make it well suited for application in harsh environments and *in vivo* conditions.

The electrochemical behavior of the diamond electrode is governed by its physicochemical properties, which in turn is largely influenced by the CVD deposition process. Variation of deposition parameters and types of plasma used can be manipulated to affect the morphology of the diamond crystallites and thus cause a modification of the surface chemistry which will determine the course of application. This work reports on the effects of grain size reduction on the electroanalytical performance of conductive diamond electrode deposited in  $CH_4/H_2$  gas mixture. Grain size reduction was achieved by decreasing the  $CH_4$  flow rate while keeping other fabrication parameters constant. The diamond deposition was performed at microwave power 5 kW, temperature 800° C, pressure 120 torr,  $H_2$  flow rate 478 sccm, and varying  $CH_4$  flow rate 15, 10, 5 and 1 sccm. Boron doping was achieved using a p-type gaseous dopant; trimethylboron (TMB) = 20 sccm. Diamond deposition duration was two hours.

Figure 1 (a) shows the SEM micrographs of diamond electrodes deposited using 15, 10, 5 and 1 sccm CH<sub>4</sub>. Diamond crystallites transitioned from microcrystalline to nanocrystalline when CH<sub>4</sub> flow rates were decreased. Nanocrystallinity of diamond electrode was achieved at CH<sub>4</sub> = 1 sccm as supported by Raman spectroscopy. Figure 1 (b) shows the Raman spectra of the four diamond electrodes. As CH<sub>4</sub> flow rate was decreased, the diamond peak at 1332 cm<sup>-1</sup> broadened due to reduction in grain size and increase in defects [2]. The peak intensity at ~1615 cm<sup>-1</sup> results from graphitic sp<sup>2</sup> bonds at the grain boundary [2]. As microcrystalline diamond (MCD) transitioned into nanocrystalline diamond (NCD), the fraction of grain boundary increased thus causing the ratio of  $I_{1332}/I_{1615}$  to fall. At CH<sub>4</sub> = 1 sccm, the diamond peak was less resolved. Additional peaks were also observed and two of importance are the shoulders at ~1160 cm<sup>-1</sup> and ~1450 cm<sup>-1</sup> which were characteristic of NCD [3].

Figure 2 (a)(i) shows the cyclic voltammograms for the redox reaction of 1 mM Fe(CN)<sub>6</sub><sup>4-</sup> in 0.1 M KNO<sub>3</sub> at a scan rate of 10 mV/s for the four electrodes. A plot of oxidation peak current,  $i_{p,ox}$  vs. square root of scan rate,  $v^{1/2}$  is linear (not shown), indicative of linear diffusion-controlled process. Table 1 shows that the diamond electrodes displayed higher resistance (R), lower oxidation peak current ( $i_{p,ox}$ ) and larger peak separation ( $\Delta E_p$ ) for oxidation of ferrocyanide, Fe(CN)<sub>6</sub><sup>4-</sup> with decreasing grain size. The electroanalytical performance of the diamond electrode for this redox species deteriorated with decreasing grain size. This shows that the properties of NCD electrodes fabricated in this manner does not support redox reaction of ferrocyanide. However, as the NCD electrode has different surface chemistry from that of MCD, it may find utility in sensing other analytes whose electrochemical reaction is usually not favored on MCD. Figure 2 (b) shows the cyclic voltammogram for 1 mM dopamine (DA) in PBS buffer, pH = 7.2 at a scan rate of 100 mV/s using an independent high-quality, hydrogen-terminated MCD electrode. As expected, it's redox reaction at the MCD electrode is very sluggish with  $\Delta E_p = 350$  mV while the kinetics of Fe(CN)<sub>6</sub><sup>4-</sup> at the same electrode was reversible with  $\Delta E_p \sim 60$  mV (figure 2 (a)(ii)). Detailed comparison of the electroanalytical performance of the four electrodes for sensing of DA will also be presented.

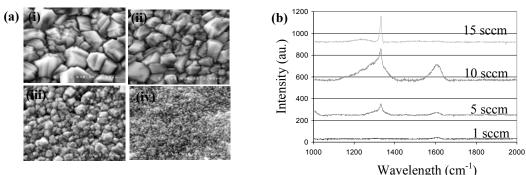


Figure 1. (a): SEM micrograph of diamond electrodes deposited at various CH<sub>4</sub> flow rate: (i) 15 sccm, (ii) 10 sccm, (iii) 5 sccm, and (iv) 1 sccm. TMB = 20 sccm, H<sub>2</sub> = 478 sccm, microwave power = 5 kW, pressure = 120 torr, temperature = 800 °C; (b) Raman spectra of diamond electrodes deposited with various CH<sub>4</sub> flow rate.

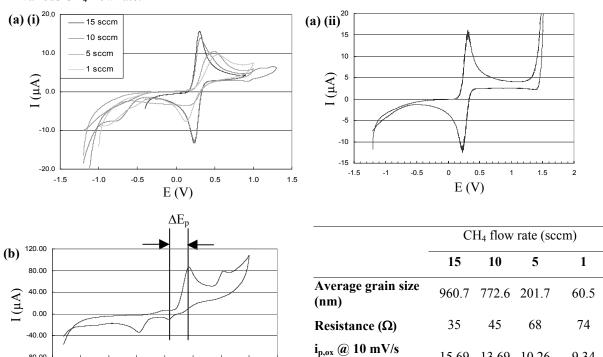


Figure 2. Cyclic voltammogram of (a): 1 mM  $Fe(CN)_6^{4}$ in  $0.1 \text{ M KNO}_3$  at scan rate = 10 mV/s for (i): diamond electrodes with various CH<sub>4</sub> flow rate, and (ii): an independent MCD electrode; (b): 1mM DA in PBS, pH = 7.2 at scan rate = 100 mV/s for independent MCD.

-0.5

0

E (V)

0.5

Table 1. Effect of methane flow rate on grain size, film resistance, oxidation peak current, ip,ox and peak separation,  $\Delta E_p$ .

15.69

67

13.69

77

10.26

350

9.34

406

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-80.00

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 $(\mu A)$ 

(mV)

 $\Delta E_p @ 10 \text{ mV/s}$ 

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